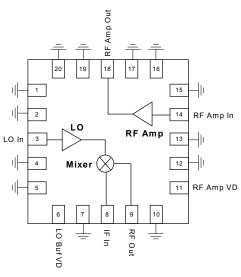


Advance Information RFS5007

5.1-5.9 GHz U-NII Upconverter

Applications

- U-NII band RF upconverter
- ISM band transmitter equipment
- 802.11a, HIPERLAN/2 transmitter

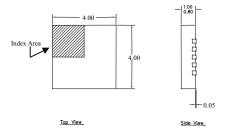


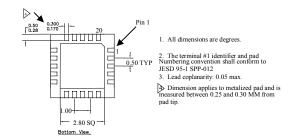
M Product Description

The RFS5007 upconverter is a high-performance GaAs MESFET IC designed for transmitter applications in the 5.1-5.9 GHz (U-NII) frequency band. With high input IP3, the part is ideal for fixed wireless and WLAN applications. The RFS5007 combines a double-balanced mixer, LO buffer and RF amplifier in a single low-cost surface-mount package. All RF, IF and LO ports are internally matched to 50 ohms and the IC operates off of a single 5V supply.

Product Features

- Single-chip RF U-NII upconverter
- Matched to 50 ohms
- 15 dBm mixer input IP3





4mm Package Outline



Advance Information RFS5007

5.1-5.9 GHz U-NII Upconverter

	Specification				
Parameter ¹	Min.	Тур.	Max.	Unit	Condition
Overall					
RF Frequency Range	5150		5850	MHz	
LO Frequency Range	5000		6000	MHz	
IF Frequency Range	100	_	900	MHz	
Cascaded Gain		-6 8		dB	
Cascaded Output P _{1dB}		8		dBm	
RF Amplifier					
Noise Figure		5 7		dB	
Gain				dB	
Output IP3		15		dBm	
Gain Flatness		±0.5		dB	Over a 100 MHz bandwidth
Reverse Isolation		35		dB	
Input Return Loss	10			dB	
Output Return Loss	10			dB	
Current Consumption		30		mA	
LO Input					
LO Input Level		5		dB	
Input Return Loss	10			dB	
Current Consumption		30		mA	
Mixer					
Noise Figure	12	13	14	dB	
Input IP3		15		dBm	
Conversion Gain	-12	-13	-14	dB	IF=400 MHz
Gain Flatness		±0.5		dB	Over a 100 MHz bandwidth
IF Return Loss	10			dB	
RF Return Loss	10			dB	
LO-RF Isolation	30	35	40	dB	LO Power at mixer=15 dBm
Power Supply					
Operating Voltage		5		V	
Current Consumption	DE 5775	60		mA	5 ID T 250 C 1 1

Note 1: Test Conditions: Vdd=5.0 V, RF=5775 MHz, LO=5375 MHz, IF=400 MHz, LO input=5 dBm, T=25° C, unless otherwise specified.

Absolute Maximum Ratings

- / toodiate maximum ratinge					
Parameter	Rating	Unit			
DC Power Supply	8.0	V			
Operating Ambient Temperature	-40 to +85	°C			
Storage Temperature	-55 to +150	°C			
Maximum RF input level	+10	dBm			



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